

Product specification IC24 Data Handbook 1997 Jun 30



Philips Semiconductors



74LVC32A

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- In accordance with JEDEC standard no. 8-1A.
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

DESCRIPTION

The 74LVC32A is a high-performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC32A provides the 2-input OR function.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	$\begin{array}{l} C_{L}=50 \text{ pF};\\ V_{CC}=3.3 \text{ V} \end{array}$	2.6	ns
Cl	Input capacitance		5.0	pF
C _{PD}	Power dissipation capacitance per gate	Notes 1 and 2	28	pF

NOTES:

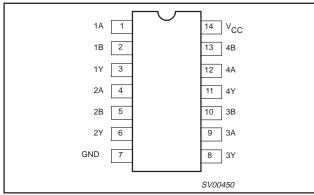
1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W) P_D = C_{PD} × V_{CC}² × f_i + \sum (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacity in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V; \sum (C_L × V_{CC}² × f_o) = sum of the outputs.

2. The condition is $V_1 = GND$ to V_{CC} .

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVC32A D	74LVC32A D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC32A DB	74LVC32A DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC32A PW	74LVC32APW DH	SOT402-1

PIN CONFIGURATION

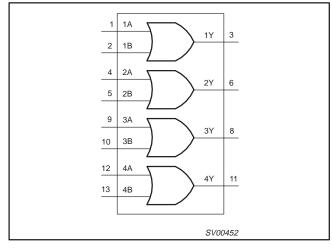


PIN DESCRIPTION

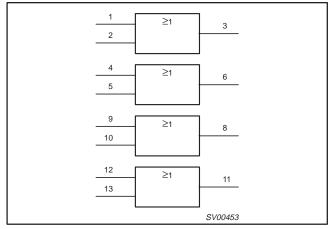
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 4, 9, 12	1A – 4A	Data innuta
2, 5, 10, 13	1B – 4B	Data inputs
3, 6, 8, 11	1Y – 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

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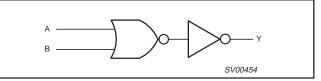
LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



LOGIC DIAGRAM (ONE GATE)



FUNCTION TABLE

INP	OUTPUTS	
nA	nB	nY
L	L	L
L	н	Н
Н	L	Н
Н	Н	н

NOTES:

H = HIGH voltage level L = LOW voltage level

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT		
STMBOL	PARAMETER	CONDITIONS	MIN	MAX		
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V	
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V	
VI	DC input voltage range		0	5.5	V	
Vo	DC output voltage range; output HIGH or LOW state		0	V _{CC}	V	
T _{amb}	Operating ambient temperature range in free-air		-40	+85	°C	
t _r , t _f	Input rise and fall times	V _{CC} = 1.2 to 2.7V V _{CC} = 2.7 to 3.6V	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER CONDITIONS		RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	$V_{I} < 0$	-50	mA
VI	DC input voltage	Note 2	-0.5 to +6.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
V _O	DC output voltage; output HIGH or LOW state	Note 2	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	± 50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

			L						
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	דואט					
			MIN	TYP ¹	MAX	1			
M		V _{CC} = 1.2V	V _{CC}						
V _{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0						
M		V _{CC} = 1.2V			GND	v			
V _{IL}	LOW level Input voltage	V _{CC} = 2.7 to 3.6V			0.8	1 [×]			
V _{OH}		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -12mA$	V _{CC} -0.5			1			
	HIGH level output voltage	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -100\mu A$	V _{CC} -0.2	V _{CC}					
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = -18mA$	V _{CC} -0.6			1 `			
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24mA$	V _{CC} -0.8			1			
		$V_{CC} = 2.7V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 12mA$			0.40				
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V			
		$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 24mA$			0.55	1			
ł	Input leakage current	$V_{CC} = 3.6V; V_{I} = 5.5V \text{ or GND}$		±0.1	±5	μΑ			
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μA			
ΔI_{CC}	Additional quiescent supply current per input pin	V_{CC} = 2.7V to 3.6V; $V_{\rm I}$ = V_{CC} –0.6V; $I_{\rm O}$ = 0		5	500	μA			

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC CHARACTERISTICS

GND = 0 V; t_r = $t_f\,\leq\,$ 2.5 ns; C_L = 50 pF

SYMBOL PARAMETER			LIMITS							
		WAVEFORMS	RMS V _{CC} = 3.3V ±0.3V		V _{CC} = 2.7V			V _{CC} = 1.2V	UNIT	
			MIN	TYP ¹	MAX	MIN	TYP	MAX	TYP	
t _{PHL} / t _{PLH}	Propagation delay nA, nB to nY	1, 2	1.5	2.6	4.9	1.5	3.0	5.9	16	ns

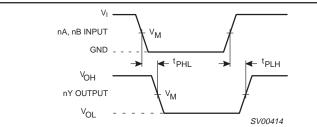
NOTE:

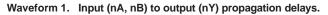
1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

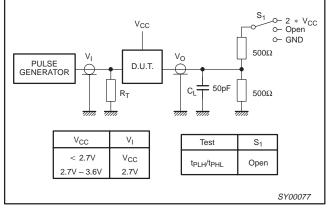
 $\begin{array}{l} V_M = 1.5 \ V \ at \ V_{CC} \ \geq \ 2.7 \ V \\ V_M = 0.5 \ \bullet \ V_{CC} \ at \ V_{CC} < 2.7 \ V \end{array}$

 $V_{\mbox{OL}}$ and $V_{\mbox{OH}}$ are the typical output voltage drop that occur with the output load.



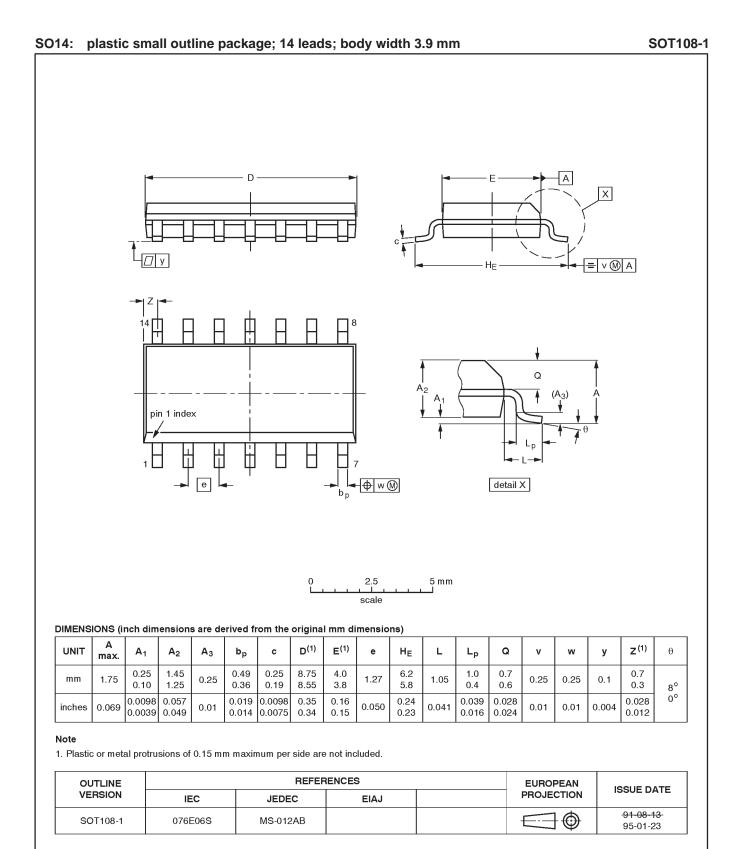


TEST CIRCUIT

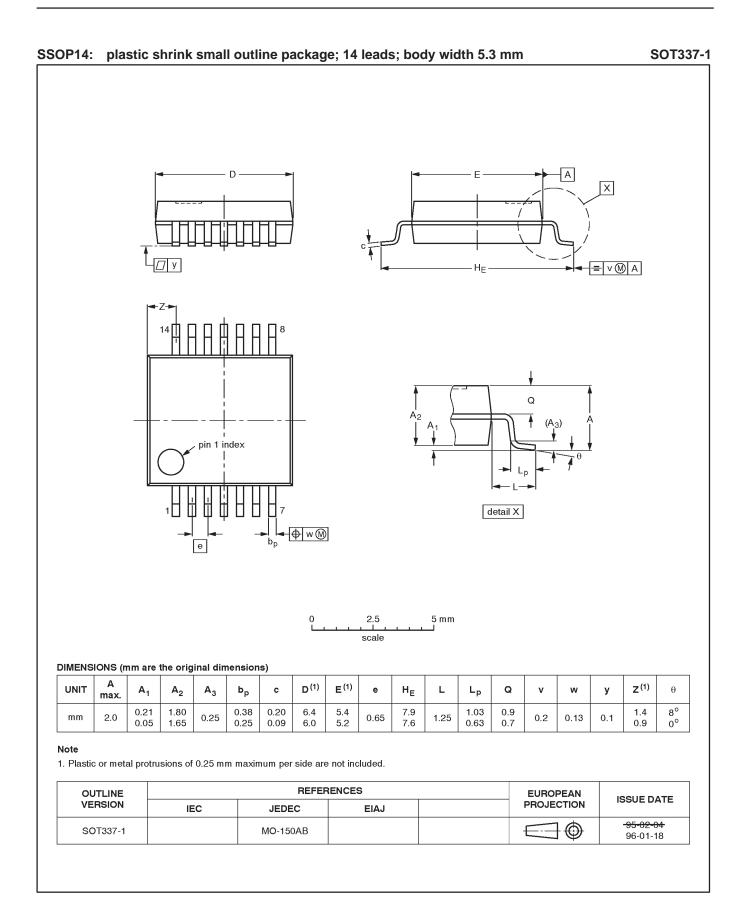


Waveform 2. Load circuitry for switching times.

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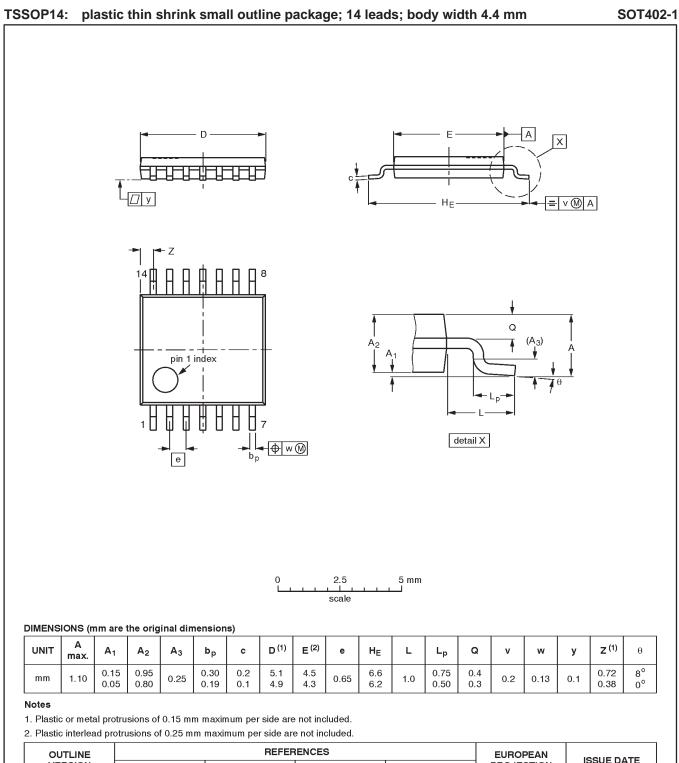


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NOTES

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DEFINITIONS						
Data Sheet Identification Product Status Definition						
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		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
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